



2SK3487 — N-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 2.5V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		20	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	I _D		8	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	32	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (250mm ² ×0.8mm)	1.5	W
		T _c =25°C	3.5	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =1mA, V _{GS} =0	20			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	y _{fs}	V _{DS} =10V, I _D =4A	7.2	12		S
Static Drain-to-Source On-State Resistance	R _{DS(on) 1}	I _D =4A, V _{GS} =4V		25	33	mΩ
	R _{DS(on) 2}	I _D =2A, V _{GS} =2.5V		33	47	mΩ
Input Capacitance	C _{iss}	V _{DS} =10V, f=1MHz		1000		pF
Output Capacitance	C _{oss}	V _{DS} =10V, f=1MHz		210		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} =10V, f=1MHz		150		pF

Marking : LD

Continued on next page.

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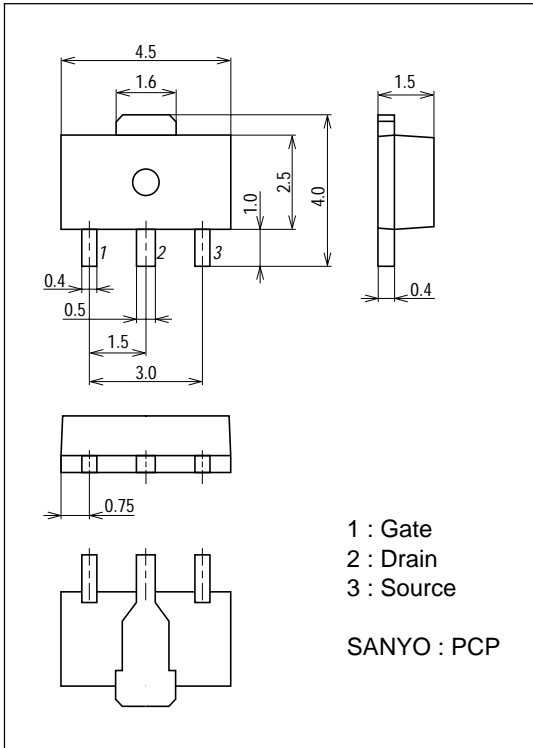
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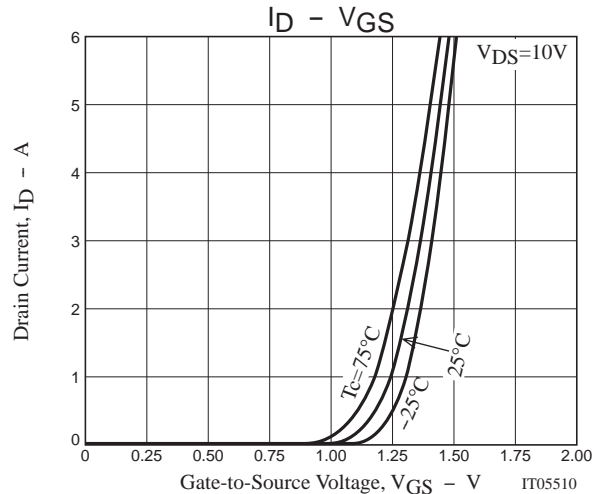
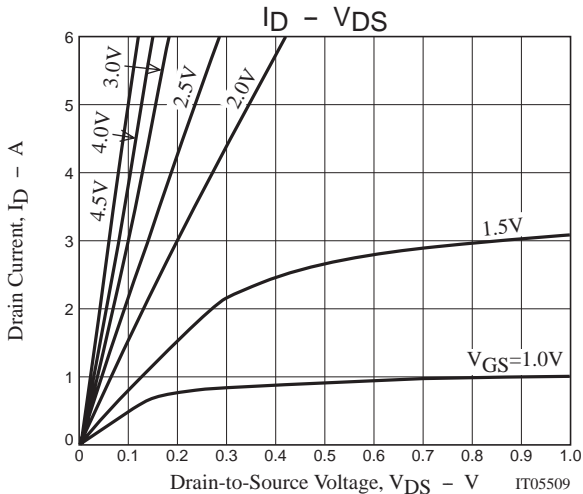
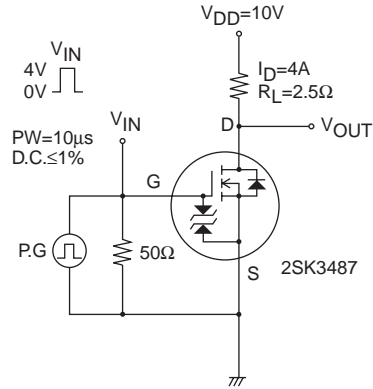
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Turn-ON Delay Time	$t_d(\text{on})$	See specified Test Circuit.		10		ns
Rise Time	t_r	See specified Test Circuit.		60		ns
Turn-OFF Delay Time	$t_d(\text{off})$	See specified Test Circuit.		27		ns
Fall Time	t_f	See specified Test Circuit.		32		ns
Total Gate Charge	Q_g	$V_{DS}=10V, V_{GS}=4V, I_D=8A$		14		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS}=10V, V_{GS}=4V, I_D=8A$		2.2		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS}=10V, V_{GS}=4V, I_D=8A$		3.9		nC
Diode Forward Voltage	V_{SD}	$I_S=8A, V_{GS}=0$		0.90	1.2	V

Package Dimensions

unit : mm
2062B

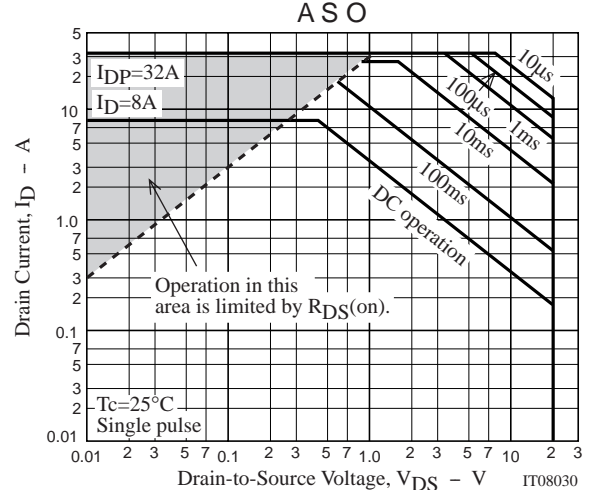
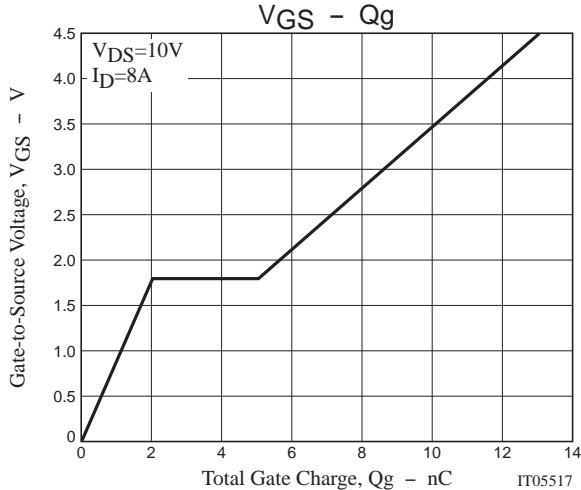
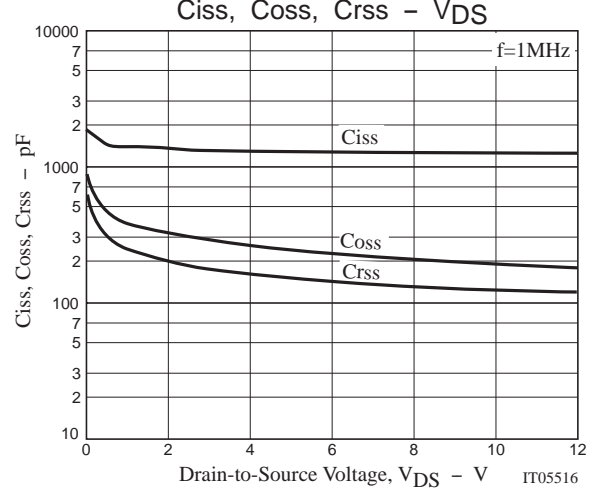
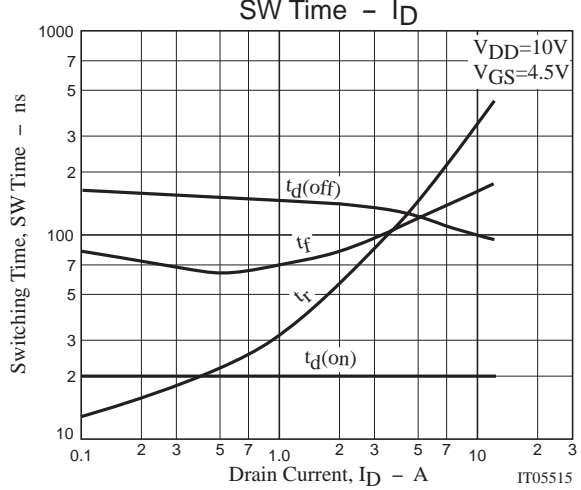
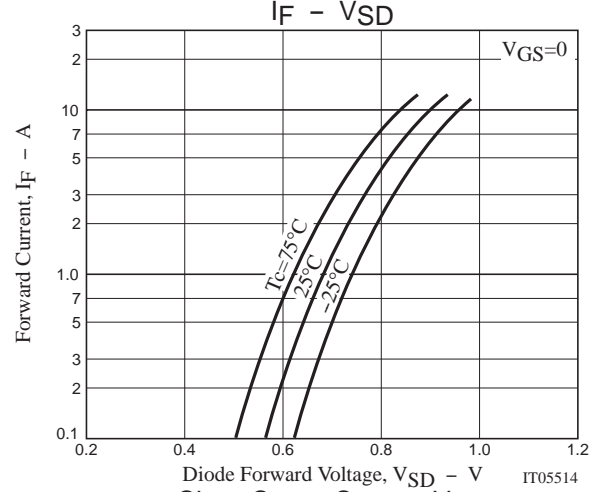
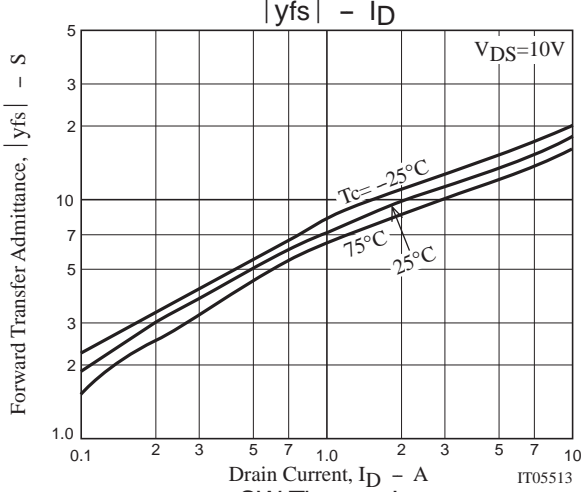
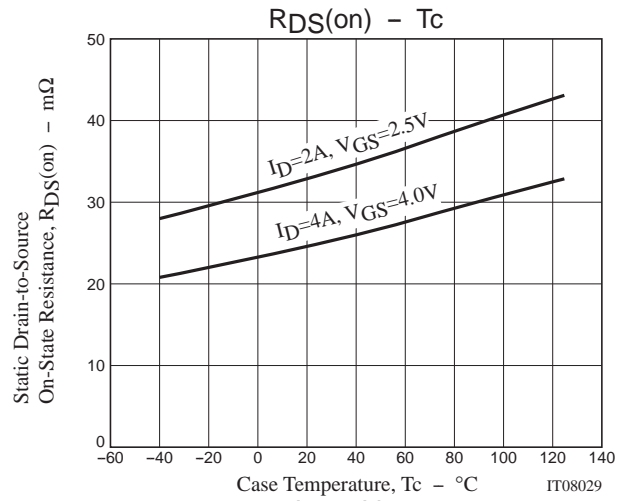
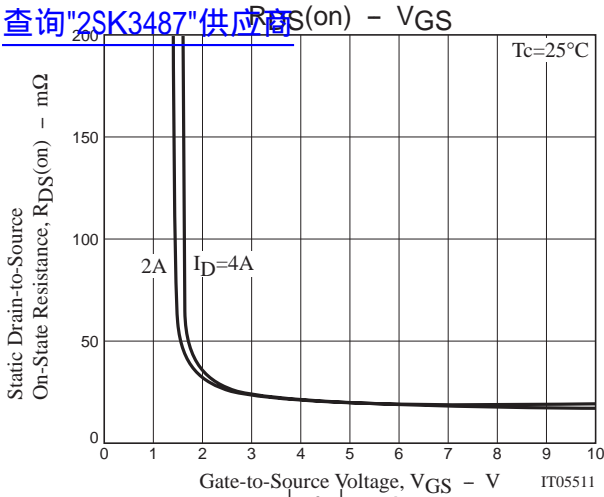


Switching Time Test Circuit

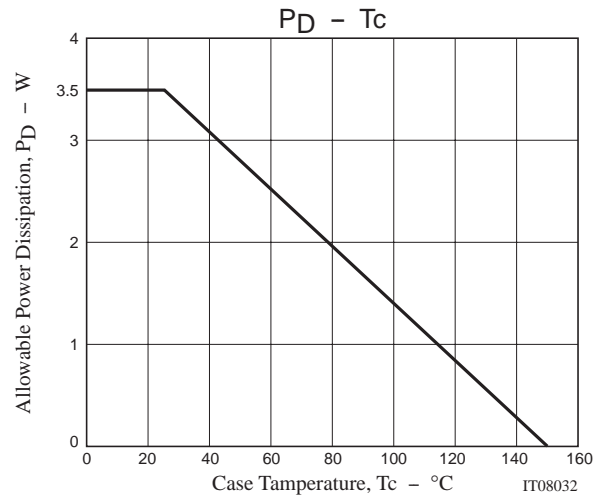
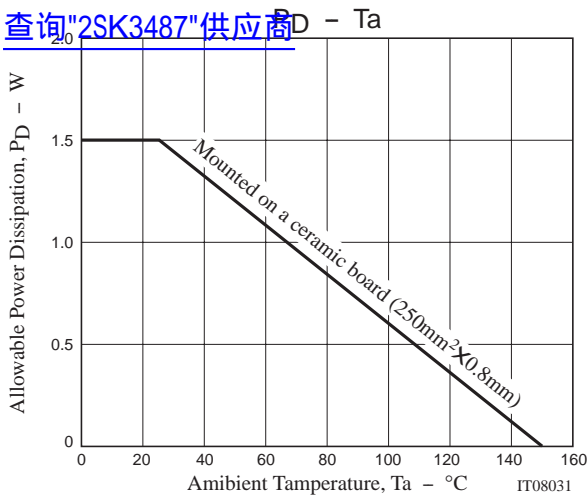


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Note on usage : Since the 2SK3487 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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